Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	6247	(cross-link cross-linked cross-linking) with UV	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 16:23
L3	4	(US-20050008880-\$ or US-20050161666-\$).did. or (US-5178959-\$ or US-6259506-\$). did.	US-PGPUB; USPAT	OR	OFF	2006/08/12 16:22
L5	4	(US-20050008880-\$ or US-20050161666-\$).did. or (US-5178959-\$ or US-6259506-\$). did.	US-PGPUB; USPAT	OR	OFF	2006/08/12 16:23
L6	1886	surface-coordinat\$3 or surface adj coordinat\$3	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 16:30
L7	3837	nanocrystal	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	ΘR	ON	2006/08/12 16:25
L8	22865	nanocrystal nanoparticle	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 16:25
L9	19	6 and 8	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 16:56
L10	6	6 with 8	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 16:25
L11	627	(Alivisatos scher manna) and 8	US PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 16:58
L12	90	(Alivisatos scher manna).in. and 8	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:18

L13	68	12 and (surface surfactant)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:08
L14	, 66	12 and (surface surfactant) with 8	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:08
L15	6043	(surface surfactant) with 8	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:08
L16	23-	12 and 15 and (pattern patterning patterned)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:09
L17	18	(Alivisatos scher manna).in. and expos\$3 with (mask reticule pattern)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:26
L18	4959	light-emitting and expos\$3 with (mask reticule pattern)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON A	2006/08/12 17:26
L19	326	light-emitting and exposing with (mask reticule pattern) same developing	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:27
L20	27	organic adj light-emitting and exposing with (mask reticule pattern) same developing	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ÖN	2006/08/12-17:29
L21	238	(crosslinked crosslink crosslinking cross-linked cross-link cross-linking) same exposing with (mask reticule pattern) same developing	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 17:30
L31	7	"5,534,056" and 8	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 17:55

	,					
L32	15	"5,534,056"	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 17:55
L33	6	(US-20040118448-\$ or US-20050051769-\$ or US-20040095658-\$).did: or (US-5434878-\$ or US-5253258-\$ or US-3984500-\$).did.	US-PGPUB; USPAT	OR∗	OFF	2006/08/12 19:35
L34	17	(US-20030226498-\$ or US-20030170959-\$ or US-20030145779-\$ or US-20040155517-\$ or US-20040039201-\$ or US-20050002635-\$ or US-20020155507-\$ or US-20020114998-\$ or US-20040115817-\$).did. or (US-6602671-\$ or US-6512172-\$ or US-6319426-\$ or US-6207392-\$ or US-5825790-\$ or US-5625456-\$ or US-5559057-\$ or US-5751018-\$). did.	US-PGPUB; USPAT	OR	OFF	2006/08/12 19:35
L35	15	L34 and ((CdS CdSe CdTe ZnS ZnSe ZnTe HgS HgSe HgTe GaN GaP GaAs InP InAs) or (cadmium zinc mercury) adj (sulfide selenide telluride) or (gallium indium) adj (nitride phosphide arsenide))	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 19:35
L36	3	L35 and (photocurable photocured cured photocuring curing curable)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 19:35
L37	3	(("5,448,582") or ("5,434,878") or ("6259506")).PN	US-PGPUB; USPAT; USOCR	OR	OFE	2006/08/12 19:35
L38	3	L37 and (uv or light)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 19:35
L39	15	L34 and ((CdS CdSe CdTe ZnS ZnSe ZnTe HgS HgSe HgTe GaN GaP GaAs InP InAs) or (cadmium zinc mercury) adj (sulfide selenide telluride) or (gallium indium) adj (nitride phosphide arsenide))	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR.	OFF	2006/08/12 19:35
L40	1894	UV with (cured curing curable) with energy	US-PGPUB; USPAT	OR	ON	2006/08/12 19:35

L42 954 UV with (cured curing curable) with US-PGPUB; US-PAT; US-PGPUB; US-PGPUB; US-PAT; US-PGP							
L43	L41	139			OR	ON	2006/08/12 19:35
L44	L42	954			OR	ON	2006/08/12 19:35
L45	L43	6958	((257/40) or (428/447)).CCLS.	USPAT;	OR	OFF	2006/08/12 19:35
Cured curing curable USPAT	L44	7			ADJ	OFF	2006/08/12 19:35
L47	L45	113		•	OR	ON	2006/08/12 19:35
L48 132	L46	8			OR	ON	2006/08/12 19:35
L49	L47	143	semiconductor nanocrystal.clm.		ADJ	OFF	2006/08/12 19:35
USPAT USPAT USPGPUB; OR OFF 2006/08/12 19:35 USPAT; EPO; DERWENT; IBM_TDB USPAT USPGPUB; OR ON 2006/08/12 19:35 USPAT USPA	L48	132		* ************************************	(A) 一、图 等中的	ON	2006/08/12 19:35
L51 113 semiconductor adj nanocrystal and (cured curing curable) US-PGPUB;	L49	408	semiconductor nanocrystal		ADJ	OFF	2006/08/12 19:35
L51	L50	6247	cross-linking) with UV	USPAT; EPO; DERWENT;	OR		2006/08/12 19:35
L53	L51	113	semiconductor adj nanocrystal and		OR	10 Table 19 Table 1	2006/08/12 19:35
Cross-linking) and L52	L52	30		100 100 20		ON	2006/08/12 19:35
USPAT; EPO; DERWENT; IBM_TDB US-PGPUB; USPAT; EPO; DERWENT; EPO; DERWENT; IBM_TDB L56 113 semiconductor adj nanocrystal and US-PGPUB; OR ON 2006/08/12-19:35	L53	14	•	USPAT; EPO; DERWENT;	OR	OFF	2006/08/12 19:35
L55	L54	11	L53 and solvent	10	OR	ON	2006/08/12 19:35
USPAT; EPO; DERWENT; IBM_TDB L56 113 semiconductor adj nanocrystal and US-PGPUB; OR ON 2006/08/12-19:35		4		EPO; DERWENT;			
1 1 1 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2	L55	11	L54 and cross	USPAT; EPO; DERWENT;	OR	ON	2006/08/12 19:35
	Ľ56	113			OR	ON	
L57 30 L51 and polymer with (cured curing US-PGPUB; USPAT ON 2006/08/12 19:35 USPAT	L57	30			OR	ON	2006/08/12 19:35

1674	(CdS or CdSe or CdTe or ZnS or ZnSe or ZnTe or HgS or HgSe or HgTe or GaN or GaP or GaAs or InP or InAs) with (nanoparticle nanocrystal)	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2006/08/12 19:35
223383	(cross-link crosslink cross-linked	US-PGPUB;	OR	OFF	2006/08/12 19:35
k	cross-linking)				
		•			
	المالية المناسبة المالية	IBM_TDB_			
412	L58 and L59	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2006/08/12 19:35
183	(cross-link crosslink cross-linked	US-PGPUB;	OR	OFF	2006/08/12 19:35
	cross-linking) with photocurable				
		DERWENT;			
	10 10 10 10 10 10 10 10	IBM_TDB			
28415	(cross-link crosslink cross-linked	US-PGPUB;	OR	OFF	2006/08/12 19:35
	curable cured photocurable)	EPO; DERWENT;			
		the state of the first containing	garing in the state of	SANTENNING TO S	
955			OR	OFF	2006/08/12 19:35
18	earca protoculable)	EPO;		企业	
		DERWENT;			
220		100 h 2 1 m 2	-		
338	· ·		OR	OFF	2006/08/12 19:35
		EPO;			
37800	(cross-link crosslink cross-linked	Company and the company	OP.	ACE	2006/08/12 19:35
37009	cross-linking) same (uv cure curing	USPAT;			2000/00/12/19:35
# . # . # . # . # . # . # . # . # . # .	curable cured photocurable)	EPO;		※ 野が事	
44					
86	"5,906,670" "5.888.885" "5.229	E	OR	OFF	2006/08/12 19:35
	320" "5,482,890"	USPAT; EPO;		5.1	2000/00/12 13.33
		DERWENT; IBM_TDB	0_0	į	
66661	(cross-link cross-linked cross-linking	US-PGPUB;	OR	ÔÑ .	2006/08/12 19:35
	crosslinking crosslinked crosslinks crosslink) and @pd<"19880101"	USPAT; EPO;	4 4 14 4 4 3 4 5		
	223383 412 183 28415 37809	ZnSe or ZnTe or HgSe or HgSe or HgTe or GaN or GaP or GaAs or InP or InAs) with (nanoparticle nanocrystal) 223383 (cross-link crosslink cross-linked cross-linking) 412 L58 and L59 183 (cross-link crosslink cross-linked cross-linking) with photocurable 28415 (cross-link crosslink cross-linked cross-linking) with (uv cure curing curable cured photocurable) 955 L58 and (uv cure curing curable cured photocurable) 338 (cross-link crosslink cross-linked cross-linking) and L63 37809 (cross-link crosslink cross-linked cross-linking) same (uv cure curing curable curable cured photocurable) 86 "5,906,670" "5,888,885" "5,229, 320" "5,482,890"	ZnSe or ZnTe or HgS or HgSe or HgTe or GaN or GaP or GaAs or InP or InAs) with (nanoparticle nanocrystal) 223383 (cross-link crosslink cross-linked cross-linking) 412 L58 and L59 US-PGPUB; US-PAT; EPO; DERWENT; IBM_TDB 413 (cross-link crosslink cross-linked cross-linking) with photocurable cross-linking) with photocurable (cross-linking) with (uv cure curing curable cured photocurable) 428415 (cross-link crosslink cross-linked cross-linking) with (uv cure curing curable cured photocurable) 438 (cross-link crosslink cross-linked cross-linking) with (uv cure curing curable cured photocurable) 439 US-PGPUB; US-PGPUB	ŻnSe or ZnTe or HgS or HgSe or HgTe or GaN or GaP or GaAs or InP or InAs) with (nanoparticle nanocrystal) 223383 (cross-link crosslink cross-linked cross-linking) 223383 (cross-link crosslink cross-linked cross-linking) 412 L58 and L59 412 L58 and L59 413 (cross-link crosslink cross-linked cross-linking) with photocurable US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB 414 (cross-link crosslink cross-linked cross-linking) with (uv cure curing curable cured photocurable) 415 L58 and (uv cure curing curable cured photocurable) 416 Cross-link crosslink cross-linked cross-linking) with (uv cure curing curable cured photocurable) 417 L58 and (uv cure curing curable cured photocurable) 418 Cross-link crosslink cross-linked cross-linking) and L63 419 Cross-link crosslink cross-linked cross-linking) and L63 420 Cross-link crosslink cross-linked cross-linking) same (uv cure curing curable cured photocurable) 438 Cross-link crosslink cross-linked cross-linking) same (uv cure curing curable cured photocurable) 449 Cross-link cross-linked cross-linked cross-linking) same (uv cure curing curable cured photocurable) 450 CR US-PGPUB; OR US-	ZnSe or ZnTe or HgSe or HgSe or HgTe or GaN or GaP

L68	581	UV with (cured curing curable) and	US-PGPUB;	OR	ON	2006/08/12 19:35
		L67	USPAT			